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Translating Bus Exchange Switch

7WBD383

The 7WBD383 is an advanced high-speed low-power translating bus exchange switch in ultra-small footprints.

Features

- High Speed: $t_{PD} = 0.25 \text{ ns (Max)} @ V_{CC} = 4.5 \text{ V}$
- 3 Ω Switch Connection Between 2 Ports
- Power Down Protection Provided on Inputs
- Zero Bounce
- TTL-Compatible Control Inputs
- Ultra-Small Pb-Free Packages
- These are Pb-Free Devices



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MARKING DIAGRAMS



UDFN8 MU SUFFIX CASE 517AJ





UDFN8 1.95 x 1.0 CASE 517CA





Micro8 **DM SUFFIX** CASE 846A





UQFN8 **MU SUFFIX** CASE 523AN





US8 **US SUFFIX CASE 493**



Commercial

AL, X, D383, AJ, AG

= Specific Device Code = Date Code

Α

= Assembly Location

L Υ W = Lot Code

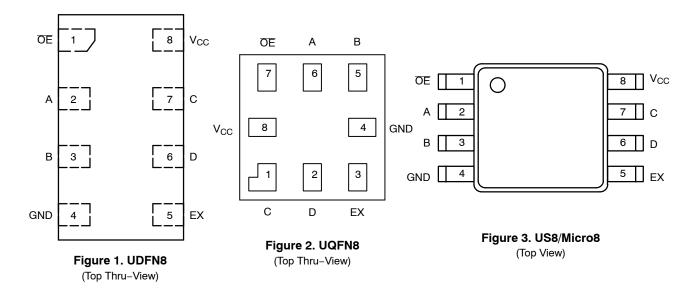
= Year Code = Week Code = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.



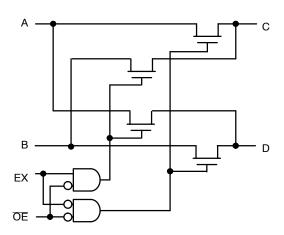


Figure 4. Logic Diagram

FUNCTION TABLE

Input OE	Input EX	Function
L	L	A = C; B = D
L	Н	A = D; B = C
Н	Х	Disconnect

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
V _{IN}	Control Pin Input Voltage		-0.5 to +7.0	٧
V _{I/O}	Switch Input / Output Voltage		-0.5 to +7.0	٧
I _{IK}	Control Pin DC Input Diode Current	V _{IN} < GND	-50	mA
I _{OK}	Switch I/O Port DC Diode Current	V _{I/O} < GND	-50	mA
Ιο	ON-State Switch Current		±128	mA
	Continuous Current Through V _{CC} or GND		±150	mA
Icc	DC Supply Current Per Supply Pin		±150	mA
I _{GND}	DC Ground Current per Ground Pin		±150	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Se	conds	260	°C
TJ	Junction Temperature Under Bias		150	°C
$\theta_{\sf JA}$	Thermal Resistance	US8 (Note 1) UDFN8 UQFN8 Micro8	251 111 208 392	°C/W
P _D	Power Dissipation in Still Air at 85°C	US8 UDFN8 UQFN8 Micro8	498 1127 601 319	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage Human Body Mode (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)		> 2000 > 200 N/A	V
I _{LATCHUP}	Latchup Performance Above V _{CC} and Below 0	GND at 125 °C (Note 5)	±200	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.
- 2. Tested to EIA / JESD22-A114-A.
- Tested to EIA / JESD22-A115-A.
 Tested to JESD22-C101-A.
- 5. Tested to EIA / JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Max	Unit
V _{CC}	Positive DC Supply Voltage		4.0	5.5	V
V _{IN}	Control Pin Input Voltage	0	5.5	V	
V _{I/O}	Switch Input / Output Voltage	0	5.5	V	
T _A	Operating Free-Air Temperature	-55	+125	°C	
Δt/ΔV	Input Transition Rise or Fall Rate Control Input Switch I/O		0 0	5 DC	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

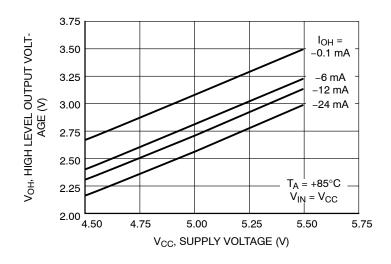
			V _{CC}	T _A = 25°C		T _A = -55°C to +125°C			
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Unit
V _{IK}	Clamp Diode Voltage	I _{I/O} = -18 mA	4.5			-1.2		-1.2	V
V _{IH}	High-Level Input Voltage (Control)		4.0 to 5.5	2.0			2.0		V
V _{IL}	Low-Level Input Voltage (Control)		4.0 to 5.5			0.8		0.8	V
V _{OH}	Output Voltage High	See Figure 5							
I _{IN}	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	5.5			±0.1		±1.0	μΑ
l _{OFF}	Power Off Leakage Current	V _{I/O} = 0 to 5.5 V	0			±0.1		±1.0	μΑ
I _{CC}	Quiescent Supply Current	$\begin{aligned} I_{O} &= 0, \\ V_{IN} &= V_{CC} \text{ or } 0 \text{ V} \\ \overline{OE} &= GND \\ \overline{OE} &= V_{CC} \end{aligned}$	5.5			±1.0 ±0.1		±1.0 ±1.0	mA μA
ΔI_{CC}	Increase in Supply Current (Control Pin)	One input at 3.4 V; Other inputs at V _{CC} or GND	5.5					2.5	mA
R _{ON}	Switch ON Resistance	V _{I/O} = 0, I _{I/O} = 64 mA I _{I/O} = 30 mA	4.5		3 3	7 7		7 7	Ω
		V _{I/O} = 2.4, I _{I/O} = 15 mA		_	15	50		50	
		V _{I/O} = 2.4, I _{I/O} = 15 mA	4.0		50	70		70	

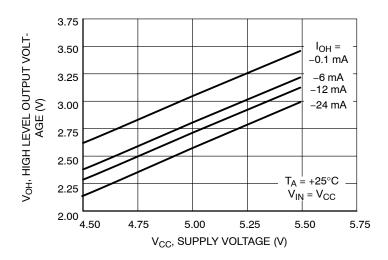
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

			V _{CC}	T _A = 25 °C		T _A = -55°C to +125°C			
Symbol	Parameter	Test Condition	(V)	Min	Тур	Max	Min	Max	Unit
t _{PD}	Propagation Delay, Bus to Bus	See Figure 6	4.0 to 5.5			0.25		0.25	ns
t _{PD-EX}	Propagation Delay, EX to Bus	See Figure 6 and Figure 7	4.0 to 5.5			4.5		4.5	ns
t _{EN}	Output Enable Time	See Figure 6	4.5 to 5.5	0.8	2.5	4.2	0.8	4.2	ns
			4.0	0.8	3.0	4.6	0.8	4.6	
t _{DIS}	Output Disable Time		4.5 to 5.5	0.8	3.0	4.8	0.8	4.8	ns
			4.0	0.8	2.9	4.4	0.8	4.4	
C _{IN}	Control Input Capacitance	V _{IN} = 5 or 0 V	5.0		2.5				pF
C _{IO(ON)}	Switch On Capacitance	Switch ON	5.0		10				pF
C _{IO(OFF)}	Switch Off Capacitance	Switch OFF	5.0		5				pF

TYPICAL DC CHARACTERISTICS





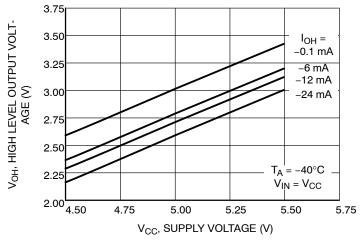
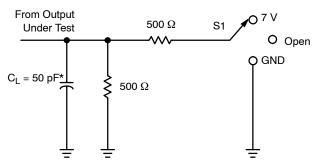


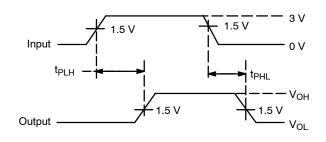
Figure 5. Output Voltage High vs Supply Voltage

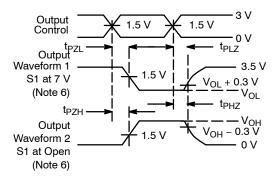
AC LOADING AND WAVEFORMS



Test	S1
t _{PD}	Open
t _{PLZ} /t _{PZL}	7 V
t _{PHZ} /t _{PZH}	Open

^{*}C_L includes probes and jig capacitance.



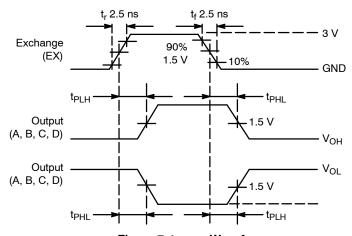


Voltage Waveforms Propagation Delay Times

Voltage Waveforms Enable and Disable Times

- 6. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control
- 7. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50~\Omega$, $t_r \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- 8. The outputs are measured one at a time, with one transition per measurement.
- 9. t_{PLZ} and t_{PHZ} are the same as t_{DIS} .
- 10. t_{PZL} and t_{PZH} are the same as t_{EN} .
- 11. t_{PHL} and t_{PLH} are the same as t_{PD}.

Figure 6. t_{PD}, t_{EN}, t_{DIS} Loading and Waveforms



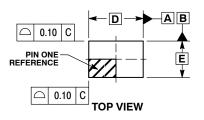
ORDERING INFORMATION

Device	Package	Shipping [†]	
7WBD383USG	US8 (Pb-Free)	3000 / Tape & Reel	
7WBD383MUTAG	UDFN8 (Pb-Free)	3000 / Tape & Reel	
7WBD383AMUTCG	UQFN8 (Pb-Free)	3000 / Tape & Reel	
7WBD383DMR2G	Micro8 (Pb-Free)	4000 / Tape & Reel	
7WBD383DMUTCG	UDFN8, 1.95 x 1.0, 0.5 mm Pitch (Pb-Free)	3000 / Tape & Reel	

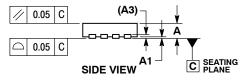
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

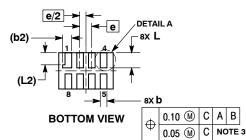
PACKAGE DIMENSIONS

UDFN8 1.8 x 1.2, 0.4P CASE 517AJ ISSUE O





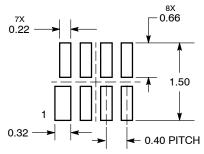




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM TERMINAL TIP.
 4. MOLD FLASH ALLOWED ON TERMINALS ALONG EOGE OF PACKAGE, FLASH MAY NOT EXCEED 0.03 ONTO BOTTOM SURFACE OF TERMINALS.
 5. DETAIL A SHOWS OPTIONAL CONSTRUCTION FOR TERMINALS.

	MILLIMETERS						
DIM	MIN	MAX					
Α	0.45	0.55					
A1	0.00	0.05					
A3	0.127	REF					
b	0.15 0.25						
b2	0.30	REF					
D	1.80	BSC					
E	1.20	BSC					
е	0.40	BSC					
L	0.45	0.55					
L1	0.00	0.03					
L2	0.40 REF						

MOUNTING FOOTPRINT* SOLDERMASK DEFINED

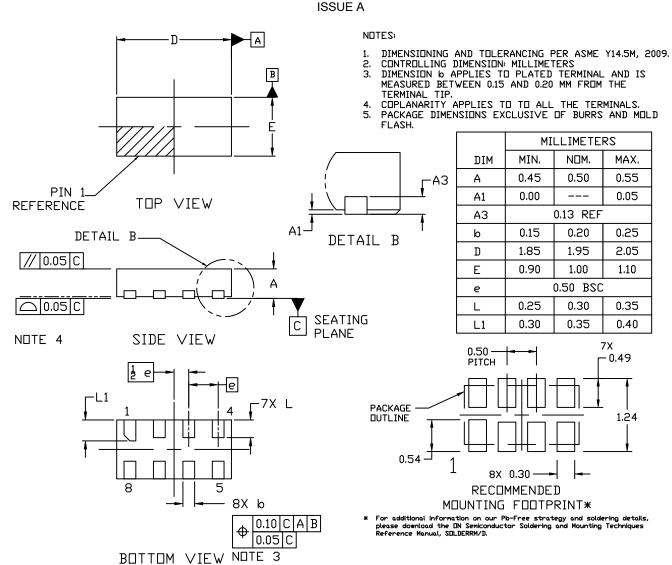


DIMENSIONS: MILLIMETERS

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

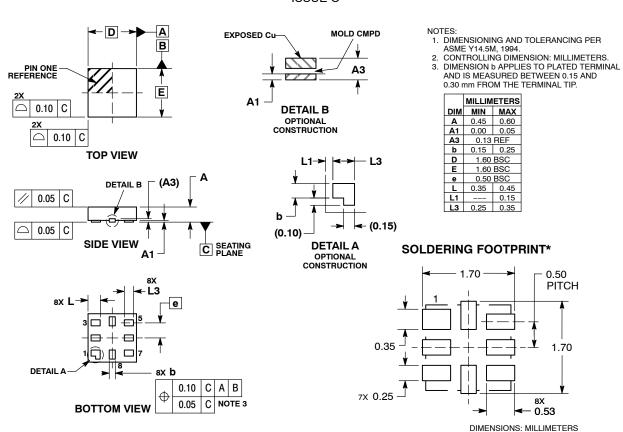
PACKAGE DIMENSIONS

UDFN8 1.95x1.0, 0.5P CASE 517CA



PACKAGE DIMENSIONS

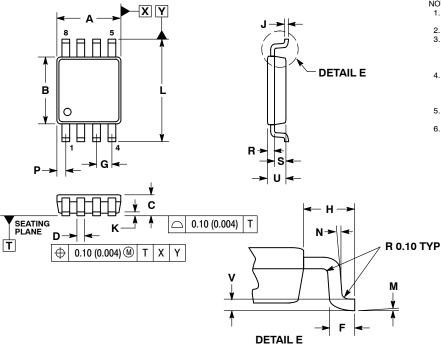
UQFN8, 1.6x1.6, 0.5P CASE 523AN ISSUE O



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

US8 **CASE 493** ISSUE D



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURR. MOLD FLASH. PROTRUSION AND GATE BURR SHALL NOT EXCEED 0.14MM (0.0055") PER SIDE.

 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH AND PROTRUSION. INTERLEAD FLASH AND PROTRUSION SHALL NOT EXCEED 0.14MM (0.0055") PER SIDE.
- (0.0055") PER SIDE.

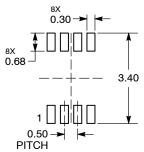
 5. LEAD FINISH IS SOLDER PLATING WITH
 THICKNESS OF 0.0076-0.0203MM (0.003-0.008").

 6. ALL TOLERANCE UNLESS OTHERWISE

•	THE TOLLTONIOL CIVIL	OC CITIEIT
	SPECIFIED ±0.0508MM ((0.0002").

	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	1.90	2.10	0.075	0.083	
В	2.20	2.40	0.087	0.094	
O	0.60	0.90	0.024	0.035	
D	0.17	0.25	0.007	0.010	
F	0.20	0.35	0.008	0.014	
G	0.50	BSC	0.020	BSC	
Н	0.40	REF	0.016	REF	
J	0.10	0.18	0.004	0.007	
K	0.00	0.10	0.000	0.004	
L	3.00	3.20	0.118	0.128	
М	0 °	6 °	0 °	6°	
N	0 °	10 °	0 °	10 °	
Р	0.23	0.34	0.010	0.013	
R	0.23	0.33	0.009	0.013	
S	0.37	0.47	0.015	0.019	
U	0.60	0.80	0.024	0.031	
٧	0.12	BSC	0.005 BSC		

RECOMMENDED SOLDERING FOOTPRINT*



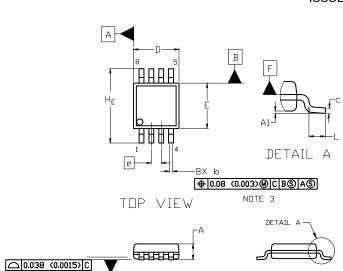
DIMENSIONS: MILLIMETERS

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

Micro8 CASE 846A ISSUE K

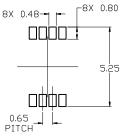
END VIEW



SIDE VIEW

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- B. DIMENSION 6 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.10 mm IN EXCESS OF MAXIMUM MATERIAL CONDITION.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 mm PER SIDE. DIMENSION E DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 mm PER SIDE. DIMENSIONS D AND E ARE DETERMINED AT DATUM F.
- 5. DATUMS A AND B ARE TO BE DETERMINED AT DATUM F.
- A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.



MILLIMETERS DIM MIN. NDM. MAX. Α 1.10 A1 0.05 0.08 0.15 b 0.25 0.33 0.40 0.13 c 0.18 0.23 D 2.90 3.00 3.10 Ε 2.90 3.00 3.10 0.65 BSC e 4.75 4.90 5.05 HE 0.40 0.70 0.55

RECOMMENDED
MOUNTING FOOTPRINT

soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

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NLSX5011MUTCG NLV9306USG NLVSX4014MUTAG NLSV4T3144MUTAG NLVSX4373MUTAG NB3U23CMNTAG
MAX3371ELT+T NLSX3013BFCT1G NLV7WBD3125USG NLSX3012DMR2G 74AVCH1T45FZ4-7 NLVSV1T244MUTBG
74AVC1T45GS-Q100H CLVC16T245MDGGREP MC10H124FNG CAVCB164245MDGGREP CD40109BPWR MC10H350FNG
MC10H125FNG MC100EPT21MNR4G MC100EP91DWG NLSX3018MUTAG NLSV2T244MUTAG NLSX3013FCT1G
NLSX5011AMX1TCG PCA9306USG SN74GTL1655DGGR SN74AVCA406LZQSR NLSX4014DTR2G NLSX3018DTR2G
LTC1045CSW#PBF LTC1045CN#PBF SY100EL92ZG 74AXP1T34GMH 74AXP1T34GNH LSF0204DPWR PI4ULS3V204LE
ADG3245BRUZ-REEL7 ADG3123BRUZ ADG3245BRUZ ADG3246BCPZ ADG3308BCPZ-REEL ADG3233BRJZ-REEL7
ADG32233BRMZ